

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	64138	TFT or "TFT" or (thin adj film\$1 adj transistor\$1) or (thin-film-transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:47			0
2	BRS	L2	652221	stress\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0
3	BRS	L3	517	1 with 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:26			0
4	BRS	L4	1	(insulat\$4 or dielectric or oxide\$1 or nitride) same power same pressure same (electrode\$1 near5 interval\$2) same continuous\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:38			0
5	BRS	L5	2029659	substrate\$1 or wafer\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0

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6	BRS	L6	40008	2 with (1 or 5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:31			0
7	BRS	L7	16936	and 1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:38			0
8	BRS	L8	2896427	power\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:39			0
9	BRS	L9	3243587	pressure\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:39			0
10	BRS	L10	17512	electrode\$1 near5 interval\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:40			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
11	BRS	L11	113308	(8 or 9 or 10) with (chang\$4 or distort\$4 or alter\$6 or modif\$5 or vary or var\$5 or adjust\$4) with (continuu\$6 or nonstop\$4 or non-stop\$4 or constant\$4 or incessant\$3 or always or endless\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:04			0
12	BRS	L12	39	11 and 7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:46			0
13	BRS	L13	65301	TFT or TFTs or "TFT" or (thin adj (film or films) adj (transistor or transistors)) or (thin-film-transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0
14	BRS	L14	2029151	substrate or substrates or wafer or wafers	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
15	BRS	L15	6619 23	stress or stresses or stressed or stressing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:50			0
16	BRS	L16	4034 5	15 with (13 or 14)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:51			0
17	BRS	L17	1752	16 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:51			0
18	BRS	L18	39	11 and 17	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:52			0

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19	BRS	L19	3275 56	(8 or 9 or 10) same (chang\$4 or distort\$4 or alter\$6 or modif\$5 or vary or var\$5 or adjust\$4) same (continuu\$6 or nonstop\$4 or non-stop\$4 or constant\$4 or incessant\$3 or always or endless\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 10:42			0
20	BRS	L20	1892	11 with (insulat\$4 or dielectric or oxide\$1 or nitride or oxynitride or oxy-nitride or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 10:45			0
21	BRS	L21	34	13 and 20	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 10:45			0
22	BRS	L22	3282 6	(8 or 9 or 10) with (chang\$4 or alter\$6 or modif\$5 or adjust\$4) with continuu\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:05			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
23	BRS	L23	121	22 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:06			0
24	BRS	L24	40	(insulat\$5 or dielectric\$1 or oxide\$1 or nitride\$1 or oxy-nitride\$1) same power same pressure same (electrode\$1 near\$5 interval\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:42			0
25	BRS	L25	5752	(changing or changed or change) with condition\$1 with continuous\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:44			0
26	BRS	L26	58	25 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:44			0

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2	BRS	L2	652221	stress\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0
3	BRS	L3	517	1 with 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:26			0
4	BRS	L4	1	(insulat\$4 or dielectric or oxide\$1 or nitride) same power same pressure same (electrode\$1 near\$5 interval\$2) same continuous\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 10:43			0
5	BRS	L5	2029659	substrate\$1 or wafer\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0

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12	BRS	L12	39	11 and 7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:46			0
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14	BRS	L14	2029151	substrate or substrates or wafer or wafers	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:49			0

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16	BRS	L16	4034 5	15 with (13 or 14)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:51			0
17	BRS	L17	1752	16 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:51			0
18	BRS	L18	39	11 and 17	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 09:52			0

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20	BRS	L20	1892	11 with (insulat\$4 or dielectric or oxide\$1 or nitride or oxynitride or oxy-nitride or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 10:45			0
21	BRS	L21	34	13 and 20	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 10:45			0
22	BRS	L22	3282 6	(8 or 9 or 10) with (chang\$4 or alter\$6 or modif\$5 or adjust\$4) with continuu\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:05			0

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23	BRS	L23	121	22 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 11:06			0